



INFORMATION DISCLOSURE CITATION

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Atty Docket No.
NOR-DF-3869 D1Serial No.
10/608,674Applicant
Henry WindischmannFiled
June 27, 2003

Group

US PATENT DOCUMENTS

Examiner Initials		Document No.	Date	Name	Class	Subclass	Filing date if approp.
★	A	4,740,263	4/88	Imai et al.	156	613	
	B	5,146,481	9/92	Garg et al.	378	35	
	C	5,206,083	4/93	Raj et al.	428	323	
	D	5,217,700	6/93	Kurihara et al.	423	446	
	E	5,221,411	6/93	Narayan	156	603	
	F	5,225,926	7/93	Cuomo et al.	359	350	
	G	5,370,299	12/94	Tanabe et al.	228	176	
	H	5,406,081	4/95	Inushima	250	338.4	
	I	5,411,797	3/96	Davanloo et al.	428	336	
	J	5,420,443	5/95	Dreifus et al.	257	77	
	K	5,427,054	6/95	Saito et al.	117	88	
	L	5,496,596	3/96	Herb et al.	427	577	
	L	5,525,815	6/96	Einset	257	77	
	M	5,628,824	5/97	Vohra et al.	117	101	
	N	5,736,252	4/98	Bigelow et al	428	408	
	O	5,747,118	5/98	Bunshah et al.	427	577	
	P	5,851,658	12/98	Yamamoto et al.	428	334	
	Q	5,904,778	5/99	Lu et al.	118	723R	
	R	5,910,221	6/99	Wu	118	723R	
	S	5,952,060	9/99	Ravi	427	577	
	T	5,955,155	9/99	Yamamoto et al.	427	577	
	U	5,916,370	6/99	Chang	118	729	
	V	6,072,275	6/00	Kobashi	313	506	
★	W	6,605,352	8/03	Windischmann	428	408	
	X						

EXAMINER

DATE CONSIDERED

7/04



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FOREIGN PATENT DOCUMENTS								
Examiner Initials		Document No.	Date	Country	Class	Sub- class	<u>Translation</u> Yes No	
A1	2A	0 449 571 A	2/91	EPO	B23B	27/14		
	2B	0 635 584 A1	1/95	EPO	C23C	16/26		
	2C	0 714 997 A1	6/96	EPO	C23C	16/26		
	2D	19603093 A1	7/97	Germany	G01F	23/22		x
	2E	7-5304	4/93	Japan	G02B	5/00		
	2F	7-45748	2/95	Japan	H01L	23/14		
	2G	9-67195	11/97	Japan	C30B	29/04		
A	2H	10-96082	4/98	Japan	C23C	16/44		
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)								
A1	AA	"Nucleation & growth of diamond films on single crystal and polycrystalline tungsten substrates"; <i>Elsevier Science Publishers</i> , vol. 9, no.3-6, April 2002 pp. 262-268						
	BB	"Nano-diamond films produced from CVD of camphor"; <i>Elsevier Science Publishers</i> , vol. 7, no. 6, June 1998, pp. 845-852						
	CC	"Diamond Growth with Boron Addition" by P. Hartmann, et al., <i>International Journal of Refractory Metals and Hard Materials</i> , Vol. 16, Issue 3, pp. 223-232, 1998						
	DD	"Ion Implantation in Predoped CVD Diamond" by H. Yagyu, et al., <i>Thin Solid Films</i> 281-282, 1996, pp. 271-274						
A1	EE	"Fabrication of Boron-doped CVD Diamond Microelectrodes" by J. Cooper et al., <i>Analytical Chemistry</i> , Vol 70, No. 3 February 1, 1998, pp. 464-467						
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